## NSN 5961-01-383-8113

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View Online at https://aerobasegroup.com/nsn/5961-01-383-8113 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** 2.5 millimeters **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case: Emitter Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 75.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 800.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: